



Product Name:	Portable Watch power bank
Product Model No.:	LS-03
	LS03
Test Auxiliary:	AC/DC Adapter, iWatch
Test Auxiliary Model No.:	HW-050450C00, AirPods 2
Transmitting mode	Keep the EUT in continuously wireless charging mode
Power supply:	Input: 5V===1A
	Output: 5V ==== 0.4A
	Output Power: 2W
197	Battery Capacity: 3.7V, 1000mAh, 3.7Wh
Test Description:	iWatch Battery > 98%, =50% and < 1% are tested, and the worst is < 1%.

Test Mod	Test Modes:						
Mode 1	Portable Watch power bank (EUT) + iWatch (2W)						
Mode 2	AC/DC Adapter + Portable Watch power bank (EUT) + iWatch (2W)	Record					
N/A	P2P2						











RF Exposure Evaluation

1 Measuring Standard

- 1.1 KDB 680106 RF Exposure Wireless Charging Apps v03r01
- 1.2 MEASUREMENT UNCERTAINTY

The reported uncertainty of measurement y ±U, where expended uncertainty U is based on a standard uncertainty multiplied by a coverage factor of k=2, providing a level of confidence of approximately 95 %.

No.	Item	Uncertainly
1	H-filed	±0.93dB
2	E-filed	±0.51dB

2 Requirements

According to the item 5 of KDB 680106 v03r01:

Inductive wireless power transfer applications that meet all of the following requirements are excluded from submitting an RF exposure evaluation.

- a) Power transfer frequency is less that 1 MHz
 - Yes. The device operates in the frequency 250KHz-350KHz
- b) Output power from each primary coil is less than or equal to 15watts.
 - Yes, The maximum output power of the primary coil is 2W.
- c) The transfer system includes onle single primary and secondary coils. This includes charging systems that may have multiple primary coils and clients that are able to detect and allow coupling only between individual pairs of coils.
- Yes. The transfer system including a charging system with only single primary coils is to detect and allow only between individual of coils
- d) Client device is placed directly in contact with the transmitter
 - Yes. Client device is placed directly in contact with the transmitter
- e) Mobile exposure conditions only (portable exposure conditions are not covered by this exclusion)
 No. The EUT has portable exposure condition.
- f) The aggregate H-Field strengths at 15 cm surrounding the device and 20 cm above the top surface form all simultaneous transmitting coils are demonstrated to be less than 50% of the MPE limit
 - Yes. Meet the requirement.

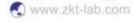
Limits

The criteria listed in the following table shall be used to evaluate the environment impact of human exposure to radio frequency (RF) radiation as specified in 1.1307(b)

Limits for Maximum Permissible Exposure (MPE)





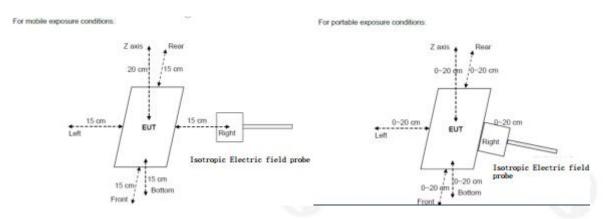




Frequency range (MHz)	Electric field strength (V/m)	Magnetic field strength (A/m)	Power density (mW/cm²)	Averaging time (minutes)							
	(A) Limits for Occupational/Controlled Exposures										
0.3-3.0	614	1.63	*(100)	6							
3.0-30	1842/f	4.89/f	*(900/f ²)	6							
30-300	61.4	0.163	1.0	6							
300-1500	/	1	f/300	6							
1500-100,000	/	Ī	5	6							
	(B) Limits for Genera	Population/Uncontrolle	ed Exposure								
0.3-1.34	614	1.63	*(100)	30							
1.34-30	824/f	2.19/f	*(180/f ²)	30							
30-300	27.5	0.073	0.2	30							
300-1500	/	1	f/1500	30							
1500-100,000	/	1	1.0	30							

F=frequency in MHz

3 Test Setup



Note: Measurements should be made from all sides and the top of the primary/client pair, with the 20 cm-0cm measured from the center of the top, and 20cm-0cm measured from the center of the rest

For mobile exposure conditions: a. The RF exposure test was performed in anechoic chamber

- b. E and H-field measurements should be made with the center of the probe at a distance of 15 cm surrounding the EUT and 20 cm above the top surface of the primary/client pair
- c. The highest emission level was recorded and compared with limit
- d. The EUT was measured according to the dictates of KDB680106 v03r01

For portable exposure conditions:

- a. The RF exposure test was performed in anechoic chamber
- b. E and H-field measurements should be made with the probe at O cmfor all side of the EUT.
- c. The highest emission level was recorded and compared with limit.

For portable exposure conditions:

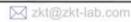
Perform H-field measurements for each edge/top surface of the host/client pair at every 2 cmstartino from as close as possible out to 10cm

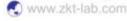
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⁼Plane-wave equivalent power density

RF exposure compliance will need to be determined with respect to 1.1307(c) and (d) of the FCC rules. The emissions should be within the limits at 300kHz in Table 1 of 1.1310(use the 300kHz limits for 150kHz:614V/m,1.63A/m).



4 Test Procedure

- 1) The RF exposure test was performed on 360 degree turn table in anechoic chamber.
- 2) 20 cm-0cm measured from the center of the top, and 20cm-0cm measured from the center of the rest sides.
- 3) The turn table was rotated 360d degree to search of highest strength.
- 4) The highest emission level was recorded and compared with limit as soon as measurement of each points were completed.
- 5) The EUT were measured according to the dictates of KDB 680106-v03

5 Test Instruments list

Test Equipment	Manufacturer	Model No.	SN.	Cal.Date (mm-dd-yy)	Cal.Due date (mm-dd-yy)
Electromagnet-ic radiation tester	WAVECONTROL	SMP 160	19SN0980	Oct. 17 2022	Oct. 16 2023
Electromagnet-ic radiation probe	WAVECONTROL	WP400-3	20WP120082	Oct. 17 2023	Oct. 16 2023











6 Test Result

H-Filed Strength at 20 cm from the edges surrounding the EUT (A/m)

Frequency Range (MHz)	Test Position Left	Test Position Right	Test Position Bottom	Test Position Rear	Test Position Front	Test Position Top	Limits (A/m)
0.250-0.350	0.18	0.17	0.16	0.19	0.20	0.19	1.63

H-Filed Strength at 20 cm from the edges surrounding the EUT (uT)

F	Test	Test	Test	Test	Test	Test	
Frequency	Position	Position	Position	Position	Position	Position	1
Range (MHz)	Left	Right	Bottom	Rear	Front	Тор	
0.250-0.350	0.23	0.21	0.20	0.24	0.25	0.24	I

H-Filed Strength at 18 cm from the edges surrounding the EUT (A/m)

Frequency Range (MHz)	Test Position Left	Test Position Right	Test Position Bottom	Test Position Rear	Test Position Front	Test Position Top	Limits (A/m)
0.250-0.350	0.22	0.23	0.21	0.24	0.22	0.25	1.63

H-Filed Strength at 18 cm from the top of the EUT (uT)

Frequency Range (MHz)	Test Position	Test Position	Test Position	Test Position	Test Position	Test Position	1
rtange (ivii iz)	Left	Right	Bottom	Rear	Front	Тор	
0.250-0.350	0.28	0.29	0.26	0.30	0.28	0.31	1

H-Filed Strength at 16 cm from the edges surrounding the EUT (A/m)

Frequency Range (MHz)	Test Position Left	Test Position Right	Test Position Bottom	Test Position Rear	Test Position Front	Test Position Top	Limits (A/m)
0.250-0.350	0.24	0.26	0.25	0.28	0.27	0.26	1.63

H-Filed Strength at 16 cm from the top of the EUT (uT)

Eroguenov	Test	Test	Test	Test	Test	Test	
Frequency Range (MHz)	Position	Position	Position	Position	Position	Position	1
Range (MHZ)	Left	Right	Bottom	Rear	Front	Тор	
0.250-0.350	0.30	0.33	0.31	0.35	0.34	0.33	1

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H-Filed Strength at 14 cm from the edges surrounding the EUT (A/m)

Frequency Range (MHz)	Test Position Left	Test Position Right	Test Position Bottom	Test Position Rear	Test Position Front	Test Position Top	Limits (A/m)
0.250-0.350	0.29	0.31	0.33	0.32	0.34	0.32	1.63

H-Filed Strength at 14 cm from the top of the EUT (uT)

Frequency	Test Position	Test Position	Test Position	Test Position	Test Position	Test Position	1
Range (MHz)	Left	Right	Bottom	Rear	Front	Top	,
0.250-0.350	0.36	0.39	0.41	0.40	0.43	0.40	1

H-Filed Strength at 12 cm from the edges surrounding the EUT (A/m)

Frequency Range (MHz)	Test Position Left	Test Position Right	Test Position Bottom	Test Position Rear	Test Position Front	Test Position Top	Limits (A/m)
0.250-0.350	0.36	0.38	0.35	0.34	0.39	0.37	1.63

H-Filed Strength at 12 cm from the top of the EUT (uT)

	Test	Test	Test	Test	Test	Test	
Frequency	Position	Position	Position	Position	Position	Position	/
Range (MHz)	Left	Right	Bottom	Rear	Front	Тор	
0.250-0.350	0.45	0.48	0.44	0.43	0.49	0.46	1

H-Filed Strength at 10 cm from the edges surrounding the EUT (A/m)

Frequency Range (MHz)	Test Position Left	Test Position Right	Test Position Bottom	Test Position Rear	Test Position Front	Test Position Top	Limits (A/m)
0.250-0.350	0.42	0.41	0.43	0.45	0.46	0.44	1.63

H-Filed Strength at 10 cm from the top of the EUT (uT)

Frequency Range (MHz)	Test Position	Test Position	Test Position	Test Position	Test Position	Test Position	1
J ()	Left	Right	Bottom	Rear	Front	Тор	
0.250-0.350	0.53	0.51	0.54	0.56	0.58	0.55	1

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H-Filed Strength at 8 cm from the edges surrounding the EUT (A/m)

Frequency Range (MHz)	Test Position Left	Test Position Right	Test Position Bottom	Test Position Rear	Test Position Front	Test Position Top	Limits (A/m)
0.250-0.350	0.47	0.49	0.50	0.52	0.51	0.48	1.63

H-Filed Strength at 8 cm from the edges surrounding the EUT (uT)

Frequency Range (MHz)	Test	Test	Test	Test	Test	Test	
	Position	Position	Position	Position	Position	Position	1
	Left	Right	Bottom	Rear	Front	Тор	
0.250-0.350	0.59	0.61	0.63	0.65	0.64	0.60	1

H-Filed Strength at 6 cm from the edges surrounding the EUT (A/m)

Frequency Range (MHz)	Test Position Left	Test Position Right	Test Position Bottom	Test Position Rear	Test Position Front	Test Position Top	Limits (A/m)
0.250-0.350	0.54	0.53	0.56	0.58	0.55	0.57	1.63

H-Filed Strength at 6 cm from the top of the EUT (uT)

Frequency Range (MHz)	Test Position Left	Test Position Right	Test Position Bottom	Test Position Rear	Test Position Front	Test Position Top	1
0.250-0.350	0.68	0.66	0.70	0.73	0.69	0.71	1

H-Filed Strength at 4 cm from the edges surrounding the EUT (A/m)

Frequency Range (MHz)	Test Position Left	Test Position Right	Test Position Bottom	Test Position Rear	Test Position Front	Test Position Top	Limits (A/m)
0.250-0.350	0.62	0.59	0.64	0.60	0.63	0.62	1.63

H-Filed Strength at 4 cm from the top of the EUT (uT)

	Test	Test	Test	Test	Test	Test	
Frequency	Position	Position	Position	Position	Position	Position	/
Range (MHz)	Left	Right	Bottom	Rear	Front	Тор	
0.250-0.350	0.78	0.74	0.80	0.75	0.79	0.78	/

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H-Filed Strength at 2 cm from the edges surrounding the EUT (A/m)

	-	_		_	-		
Frequency Range (MHz)	Test Position	Test Position	Test Position	Test Position	Test Position	Test Position	Limits
	Left	Right	Bottom	Rear	Front	Тор	(A/m)
0.250-0.350	0.67	0.65	0.66	0.69	0.68	0.67	1.63

H-Filed Strength at 2 cm from the edges surrounding the EUT (uT)

Г	Test	Test	Test	Test	Test	Test	
Frequency	Position	Position	Position	Position	Position	Position	1
Range (MHz)	Left	Right	Bottom	Rear	Front	Тор	
0.250-0.350	0.84	0.81	0.83	0.86	0.85	0.84	1

H-Filed Strength at 0 cm from the edges surrounding the EUT (A/m)

Frequency Range (MHz)	Test Position Left	Test Position Right	Test Position Bottom	Test Position Rear	Test Position Front	Test Position Top	Limits (A/m)
0.250-0.350	0.72	0.74	0.76	0.77	0.73	0.75	1.63

H-Filed Strength at 0 cm from the edges surrounding the EUT (uT)

Frequency Range (MHz)	Test	Test	Test	Test	Test	Test	
	Position	Position	Position	Position	Position	Position	/
	Left	Right	Bottom	Rear	Front	Тор	
0.250-0.350	0.90	0.93	0.95	0.96	0.91	0.94	1

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+86-755-2233 6688

Remark: A/m = uT/1.25





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6 Test Set-up Photo

Probe	Length	Width	Radius	
Flobe	2.5cm	2.5cm	1.25cm	





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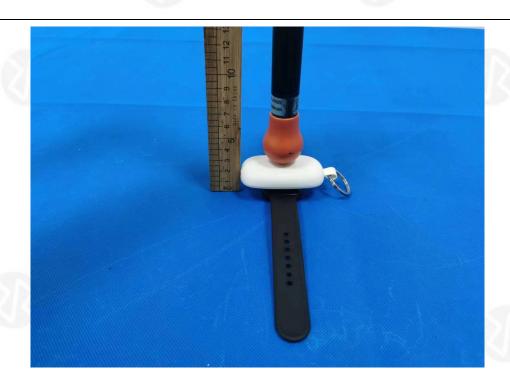




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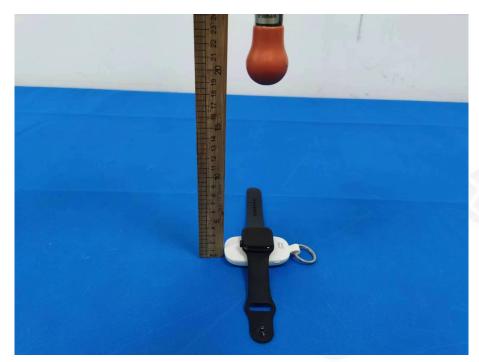


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